Preliminary

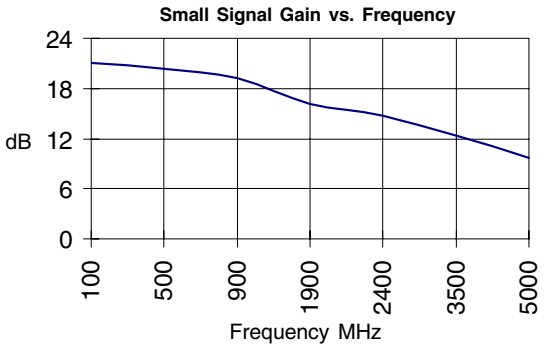
SGA-6486

DC-1800 MHz Silicon Germanium HBT Cascadeable Gain Block

Product Description

Stanford Microdevices' SGA-6486 is a high performance cascadeable 50-ohm amplifier. This RFIC uses the latest Silicon Germanium Heterostructure Bipolar Transistor (SiGe HBT) process featuring 1 micron emitters with F_T up to 65 GHz.

This circuit uses a darlington pair topology with resistive feedback for broadband performance as well as stability over its entire temperature range. Internally matched to 50 ohm impedance, the SGA-6486 requires only DC blocking and bypass capacitors for external components.



Product Features

- DC-1800 MHz Operation
- Single Voltage Supply
- High Output Intercept: +35.0 dBm typ. at 850 MHz
- High Output Power : 21.0 dBm typ. at 850 MHz
- High Gain : 19.7dB typ. at 850 MHz
- Internally Matched to 50 Ohms Input & Output

Applications

- Oscillator Amplifiers
- Final PA for Low Power Applications
- IF/ RF Buffer Amplifier
- Drivers for CATV Amplifiers

Electrical Specifications at Ta = 25C

Symbol	Parameters: Test Conditions: Z_0 = 50 Ohms, f = DC-1800 MHz		Units	Min.	Typ.	Max.
P_{1dB}	Output Power at 1dB Compression	f = 850 MHz f = 1950 MHz	dBm dBm		21.0 18.5	
S_{21}	Small Signal Gain	f = DC-1000 MHz f = 1000-2000 MHz f = 2000-5000 MHz	dB dB dB	17.5	19.7 16.7 12.3	
S_{12}	Reverse Isolation	f = DC-1000 MHz f = 1000-2000 MHz f = 2000-5000 MHz	dB dB		23.6 22.3 17.0	
S_{11}	Input VSWR	f = DC-5000 MHz	-		1.50:1	
S_{22}	Output VSWR	f = DC-5000 MHz	-		1.50:1	
IP_3	Third Order Intercept Point	f = 850 MHz f = 1950 MHz	dBm dBm		35.0 32.5	
NF	Noise Figure	f = DC-1000 MHz f = 1000-2400 MHz	dB dB		3.0 3.3	
T_D	Group Delay	f = 1000 MHz	pS		130.6	
V_D	Device Voltage		V	4.4	5.2	5.5
I_D	Device Current		mA		75	

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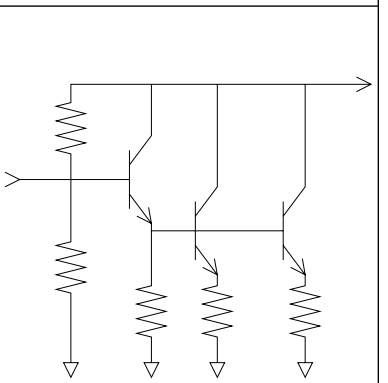
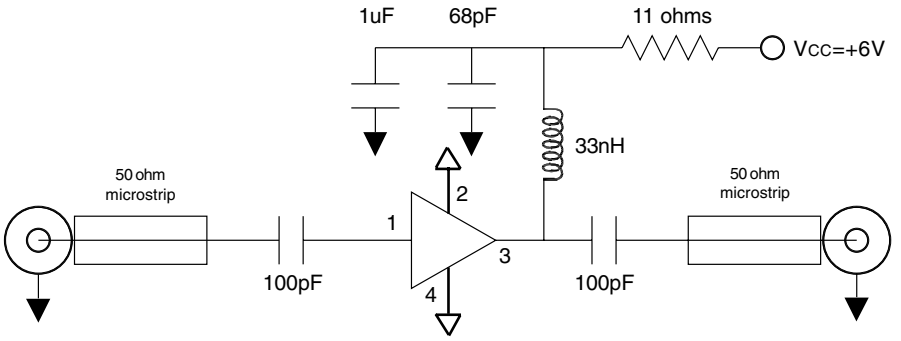
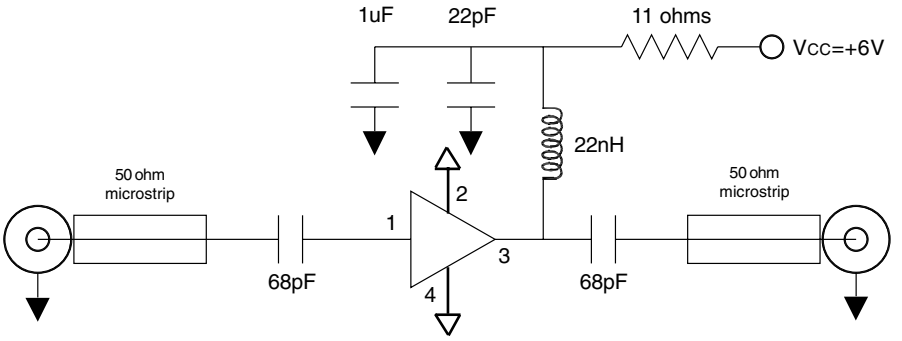
Parameter	Specification				Test Condition
	Min	Typ.	Max.	Unit	
Bandwidth					T= 25C
Frequency Range	DC		1800	MHz	
Device Bias					T= 25C
Operating Voltage		5.2		V	
Operating Current		75.0		mA	
500 MHz					T= 25C
Gain		20.3		dB	
Noise Figure		2.9		dB	
Output IP3		34.8		dBm	
Output P1dB		20.7		dBm	
Input Return Loss		23.3		dB	
Isolation		23.9		dB	
850 MHz					T= 25C
Gain		19.7		dB	
Noise Figure		3.0		dB	
Output IP3		35.0		dBm	
Output P1dB		21.0		dBm	
Input Return Loss		22.8		dB	
Isolation		23.6		dB	
1950 MHz					T= 25C
Gain		16.1		dB	
Noise Figure		3.6		dB	
Output IP3		32.5		dBm	
Output P1dB		18.5		dBm	
Input Return Loss		21.4		dB	
Isolation		21.3		dB	
2400 MHz					T= 25C
Gain		14.8		dB	
Noise Figure		3.7		dB	
Output IP3		31.4		dBm	
Output P1dB		17.2		dBm	
Input Return Loss		17.4		dB	
Isolation		19.7		dB	

Pin #	Function	Description	Device Schematic
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.	
2	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.	
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.	
4	GND	Sames as Pin 2	

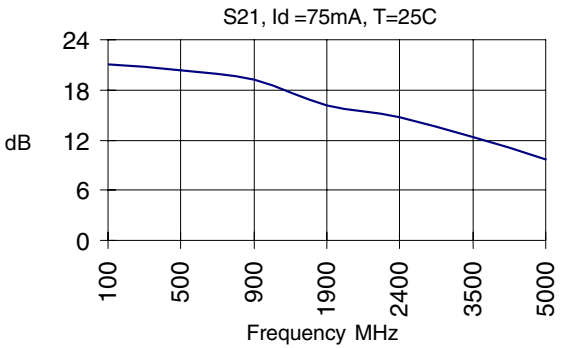
Application Schematic for +6V Operation at 900 MHz

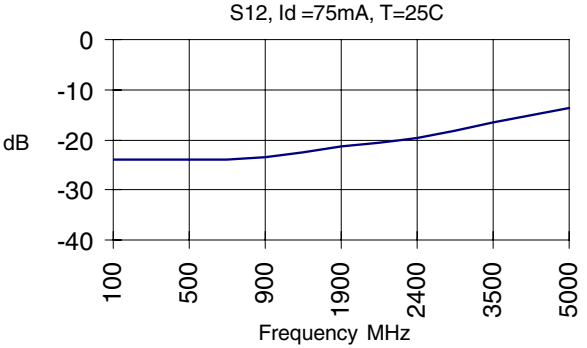


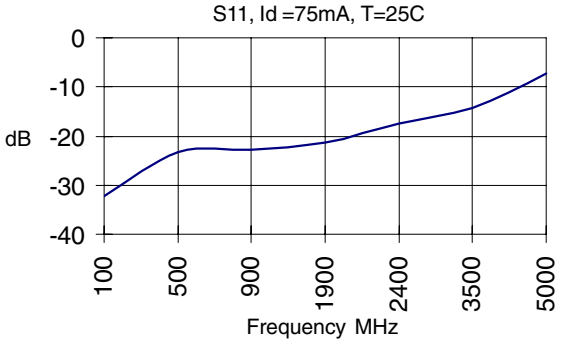
Application Schematic for +6V Operation at 1900 MHz

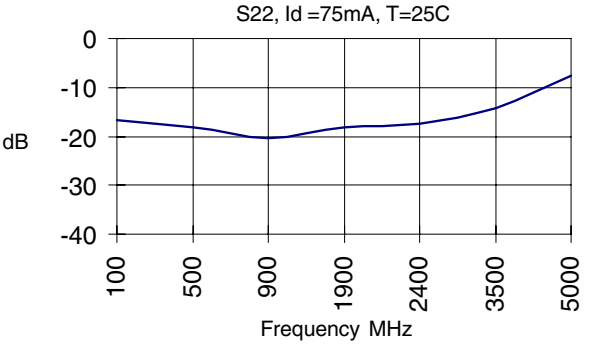


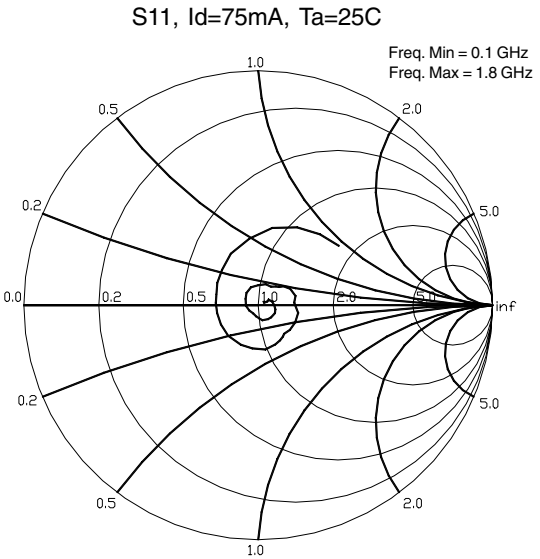
SGA-6486 DC-1800 MHz 5.2V SiGe Amplifier

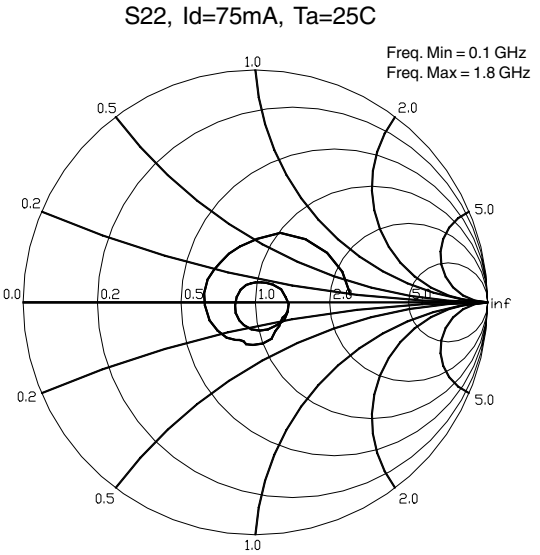












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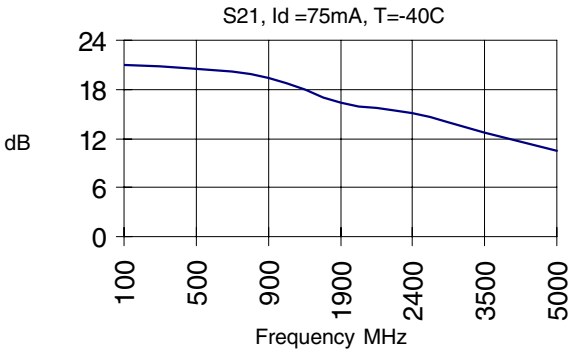

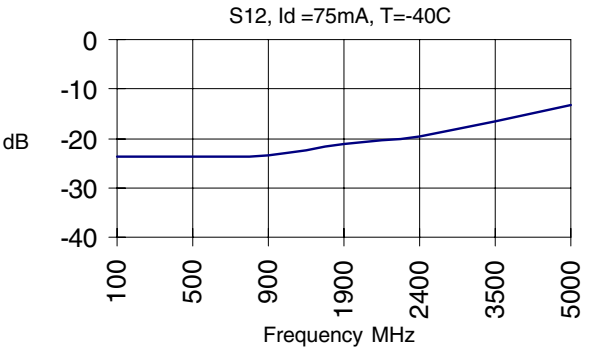

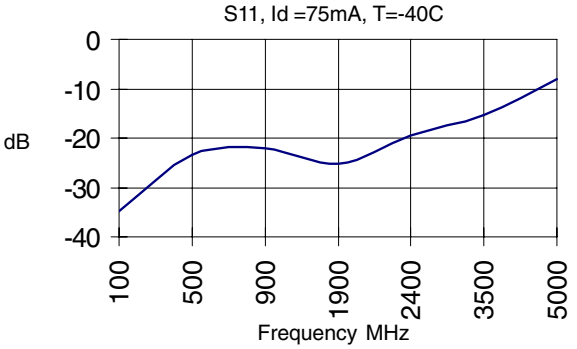

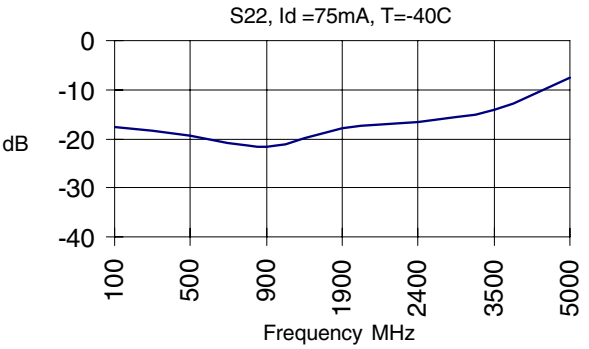

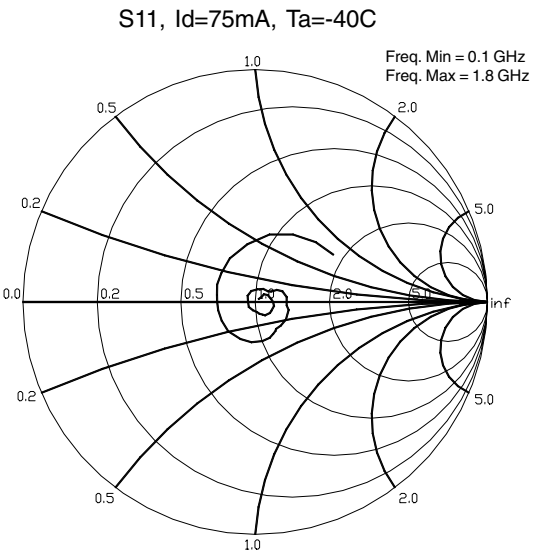

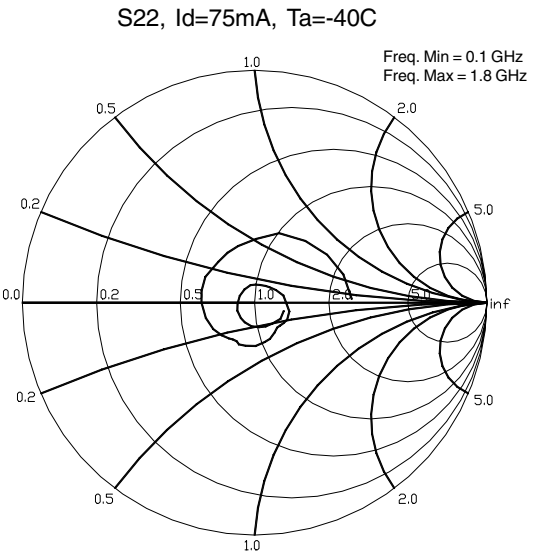

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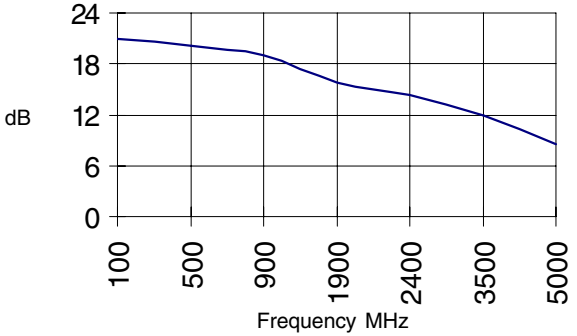
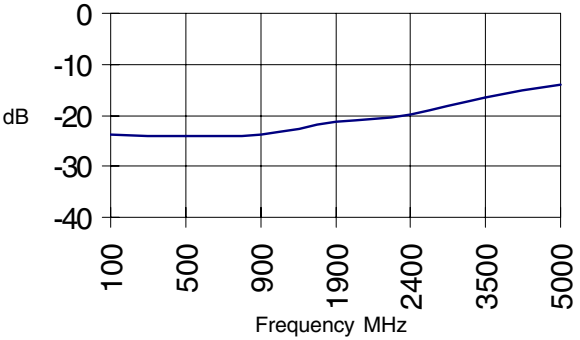
SGA-6486 DC-1800 MHz 5.2V SiGe Amplifier

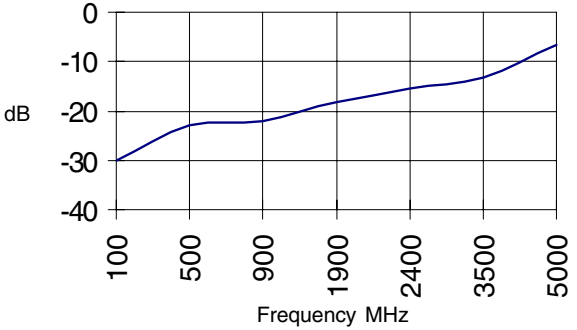
S21, Id =75mA, T=85C



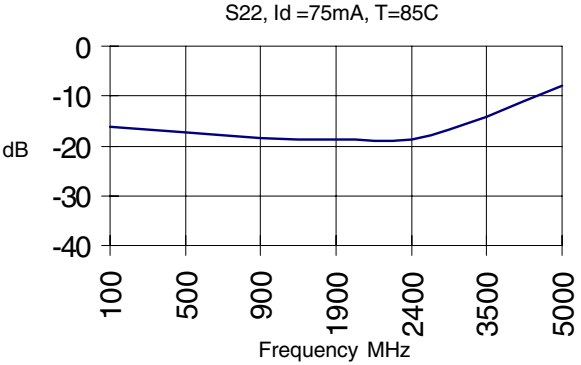
S12, Id =75mA, T=85C



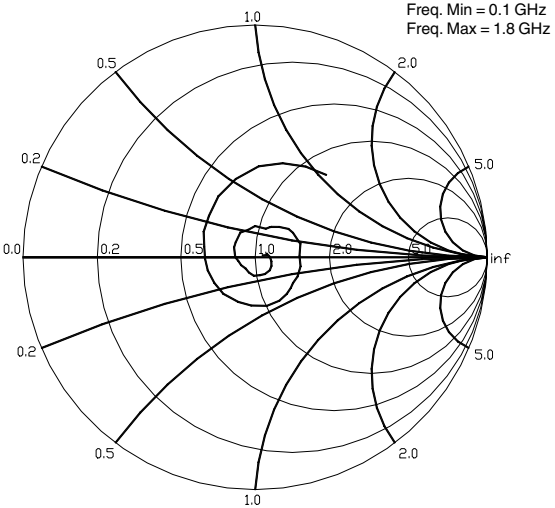
S11, Id =75mA, T=85C



S22, Id =75mA, T=85C



S11, Id=75mA, Ta=85C



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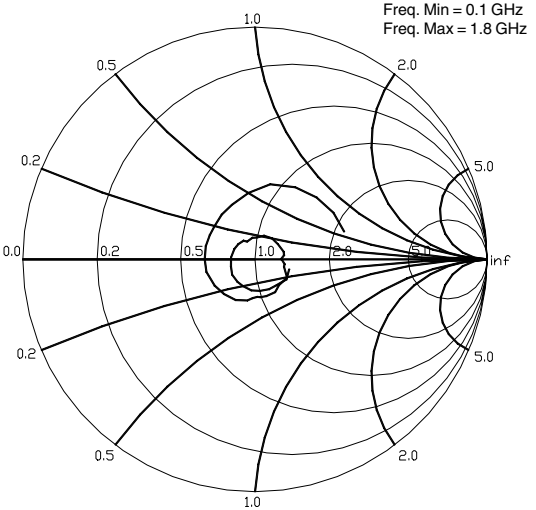

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Preliminary

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Absolute Maximum Ratings

Parameter	Value	Unit
Supply Current	160	mA
Operating Temperature	-40 to +85	C
Maximum Input Power	+10	dBm
Storage Temperature Range	-40 to +85	C
Operating Junction Temperature	+150	C

Caution:

Operation of this device above any one of these parameters may cause permanent damage. Appropriate precautions in handling, packaging and testing devices must be observed.

Thermal Resistance (Lead-Junction): 97° C/W

Part Number Ordering Information

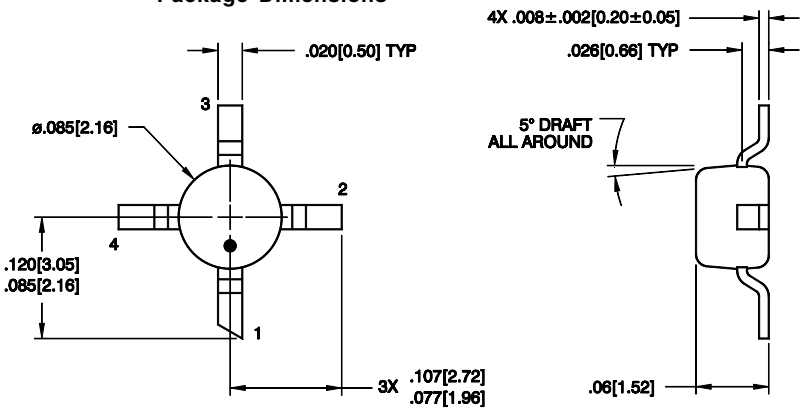
Part Number	Reel Size	Devices/Reel
SGA-6486-TR1	7"	1000
SGA-6486-TR2	13"	3000

Recommended Bias Resistor Values				
Supply Voltage(Vs)	6V	7.5V	9V	12V
Rbias (Ohms)	12.5	31	50	88

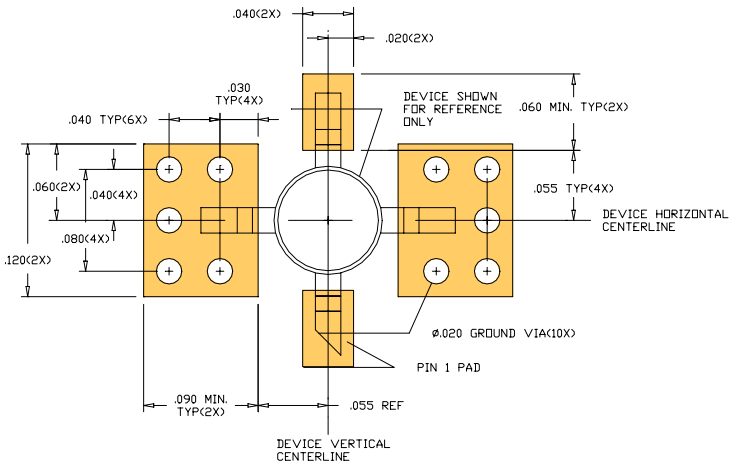
For 7.5V operation or higher, a resistor with a power handling capability of 1/2W or greater is recommended.

Package Dimensions

Pin Designation	
1	RF in
2	GND
3	RF out and Bias
4	GND



PCB Pad Layout



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